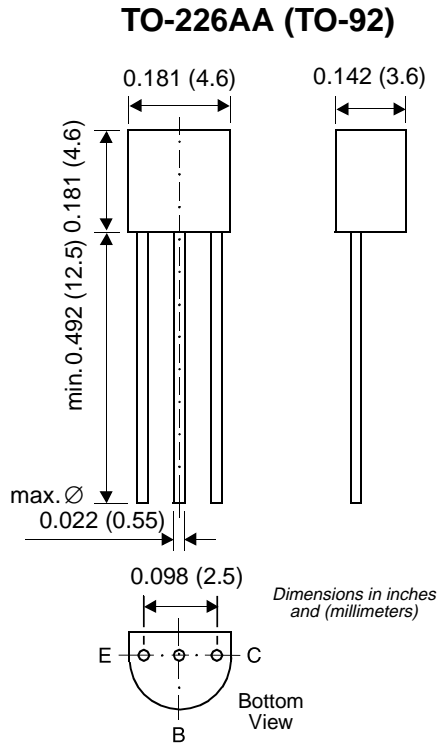
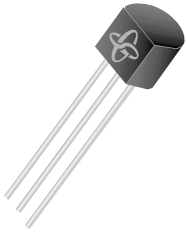


Small Signal Transistor (NPN)



New Product

Features

- NPN Silicon Epitaxial Planar Transistor for switching and amplifier applications.
- On special request, this transistor is also manufactured in the pin configuration TO-18.
- This transistor is also available in the SOT-23 case with the type designation MMBT2222A.

Mechanical Data

Case: TO-92 Plastic Package

Weight: approx. 0.18g

Packaging Codes/Options:

E6/Bulk - 5K per container

E7/4K per Ammo tape

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameters	Symbols	Value	Units
Collector-Base Voltage	V_{CB0}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current	I_C	600	mA
Power Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_{tot}	625 5.0	mW mW/°C
Power Dissipation $T_C = 25^\circ\text{C}$ Derate above 25°C	P_{tot}	1.5 12	W mW/°C
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	200	°C/W
Thermal Resistance Junction to Case	$R_{\theta JC}$	83.3	°C/W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_S	- 55 to +150	°C

Small Signal Transistor (NPN)

Electrical Characteristics (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
DC Current Gain	h _{FE}	V _{CE} = 10 V, I _C = 0.1 mA	35	—	—	—
		V _{CE} = 10 V, I _C = 1 mA	50	—	—	
		V _{CE} = 10 V, I _C = 10 mA	75	—	—	
		V _{CE} = 10 V, I _C = 10 mA T _A = -55°C	35	—	—	
		V _{CE} = 10 V, I _C = 150 mA ⁽¹⁾	100	—	300	
		V _{CE} = 1.0 V, I _C = 150 mA ⁽¹⁾	50	—	—	
		V _{CE} = 10 V, I _C = 500 mA ⁽¹⁾	40	—	—	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 10 μA, I _E = 0	75	—	—	V
Collector-Emitter Breakdown Voltage ⁽¹⁾	V _{(BR)CEO}	I _C = 10 mA, I _B = 0	40	—	—	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 10 μA, I _C = 0	6.0	—	—	V
Collector-Emitter Saturation Voltage ⁽¹⁾	V _{CEsat}	I _C = 150 mA, I _B = 15 mA I _C = 500 mA, I _B = 50 mA	0.6 —	— —	0.3 1.0	V
Base-Emitter Saturation Voltage ⁽¹⁾	V _{BEsat}	I _C = 150 mA, I _B = 15 mA I _C = 500 mA, I _B = 50 mA	0.6 —	— —	1.2 2.0	V
Collector Cut-off Current	I _{CEX}	V _{EB} = 3 V, V _{CE} = 60 V	—	—	10	nA
Collector Cut-off Current	I _{CBO}	V _{CB} = 60 V, I _E = 0 V _{CB} = 50 V, I _E = 0, T _A = 125°C	— —	— —	0.01 10	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 3 V, I _C = 0	—	—	100	nA
Base Cut-off Current	I _{BL}	V _{CE} = 60 V, V _{EB} = 3.0 V	—	—	20	nA
Input Impedance	h _{ie}	V _{CE} = 10 V, I _C = 1 mA, f = 1 kHz	2.0	—	8.0	kΩ
		V _{CE} = 10 V, I _C = 10 mA, f = 1 kHz	0.25	—	1.25	
Voltage Feedback Ratio	h _{re}	V _{CE} = 10 V, I _C = 1 mA, f = 1 kHz	—	—	8 • 10 ⁻⁴	—
		V _{CE} = 10 V, I _C = 10 mA, f = 1 kHz	—	—	4 • 10 ⁻⁴	
Current Gain-Bandwidth Product	f _T	V _{CE} = 20 V, I _C = 20 mA f = 100 MHz	300	—	—	MHz
Output Capacitance	C _{OBO}	V _{CB} = 10 V, f = 1 MHz, I _E = 0	—	—	8.0	pF
Input Capacitance	C _{IBO}	V _{EB} = 0.5 V, f = 1 MHz, I _C = 0	—	—	25	pF

Notes: (1) Pulse test: pulse width ≤ 300 μs, cycle ≤ 2%

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Electrical Characteristics (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Admittance	h _{oe}	V _{CE} = 10 V, I _C = 1 mA, f = 1 kHz	5.0	—	35	μS
		V _{CE} = 10 V, I _C = 10 mA, f = 1 kHz	25	—	200	
Small Signal Current Gain	h _{fe}	V _{CE} = 10 V, I _C = 1 mA, f = 1 kHz	50	—	300	—
		V _{CE} = 10 V, I _C = 10 mA, f = 1 kHz	75	—	375	
Collector Base Time Constant	r _b 'C _C	I _E = 20 mA, V _{CB} = 20 V, f = 31.8 MHz	—	—	150	ps
Noise Figure	NF	V _{CE} = 10 V, I _C = 100 μA, R _S = 1 kΩ, f = 1 kHz	—	—	4.0	dB
Delay Time (see Fig. 1)	t _d	I _{B1} = 15 mA, I _C = 150 mA V _{CC} = 30 V V _{BE} = -0.5 V	—	—	10	ns
Rise Time (see Fig. 1)	t _r	I _{B1} = 15 mA, I _C = 150 mA V _{CC} = 30 V V _{BE} = -0.5 V	—	—	25	ns
Storage Time (see Fig. 2)	t _s	I _{B1} = I _{B2} = 15 mA, I _C = 150 mA V _{CC} = 30 V	—	—	225	ns
Fall Time (see Fig. 2)	t _f	I _{B1} = I _{B2} = 1 mA, I _C = 10 mA V _{CC} = 30 V	—	—	60	ns

Switching Time Equivalent Test Circuit

Figure 1 - Turn-On Time

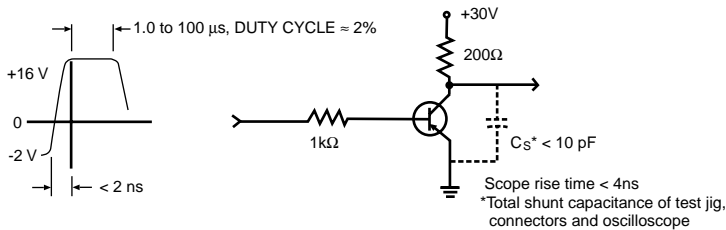


Figure 2 - Turn-Off Time

